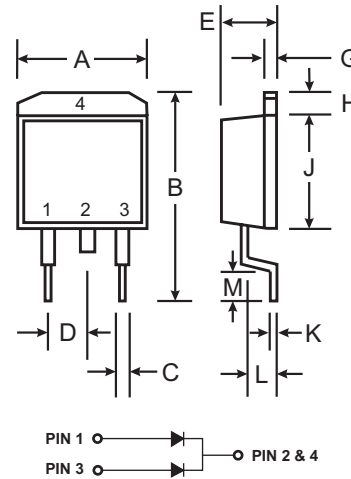


### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 125A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- **Lead Free Finish/RoHS Compliant (Note 3)**

### Mechanical Data

- Case: D<sup>2</sup>PAK
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Bright Tin. Solderable per MIL-STD-202, Method 208
- Ordering Information, Note 5, on Page 2
- Polarity: See Diagram
- Marking: Type Number
- Mounting Position: Any
- Weight: 1.7 grams (approximate)



D <sup>2</sup> PAK		
Dim	Min	Max
A	9.65	10.69
B	14.60	15.88
C	0.51	1.14
D	2.29	2.79
E	4.37	4.83
G	1.14	1.40
H	1.14	1.40
J	8.25	9.25
K	0.30	0.64
L	2.03	2.92
M	2.29	2.79
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	SBG 1030CT	SBG 1035CT	SBG 1040CT	SBG 1045CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	25	28	32	V
Average Rectified Output Current @ T <sub>C</sub> = 95°C	I <sub>O</sub>	10				A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	125				A
Forward Voltage, per Element @ I <sub>F</sub> = 5.0A	V <sub>FM</sub>	0.55				V
Peak Reverse Current @ T <sub>j</sub> = 25°C at Rated DC Blocking Voltage @ T <sub>j</sub> = 125°C	I <sub>RM</sub>	1.0 50				mA
Typical Junction Capacitance (Note 2)	C <sub>j</sub>	275				pF
Typical Thermal Resistance Junction to Case (Note 1)	R <sub>θJC</sub>	3.0				K/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +125				°C

- Notes: 1. Thermal resistance: junction to case mounted on heat sink.  
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

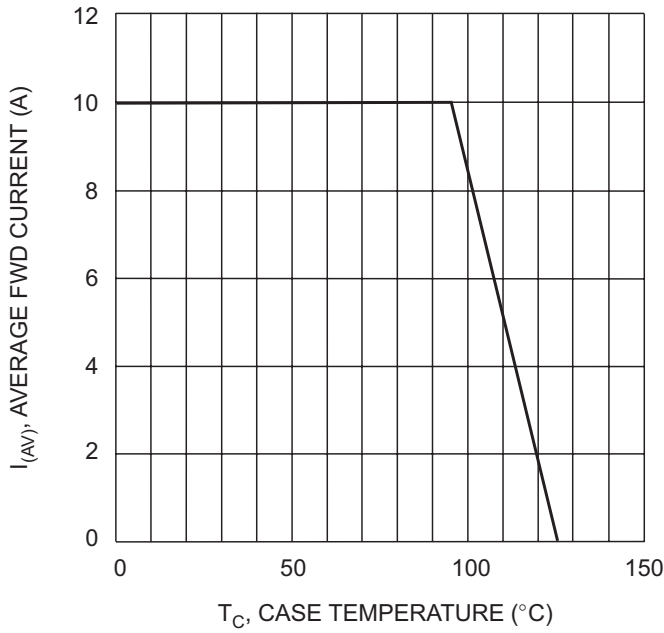


Fig. 1 Forward Current Derating Curve

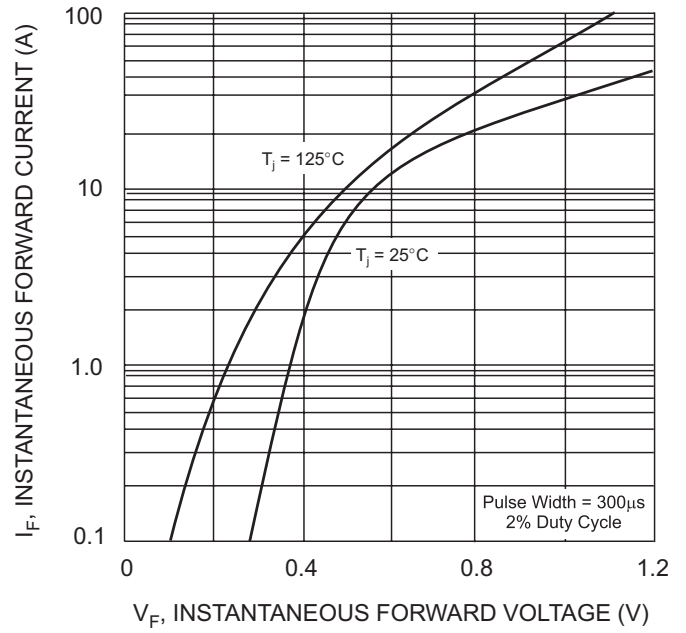


Fig. 2 Typical Forward Characteristics

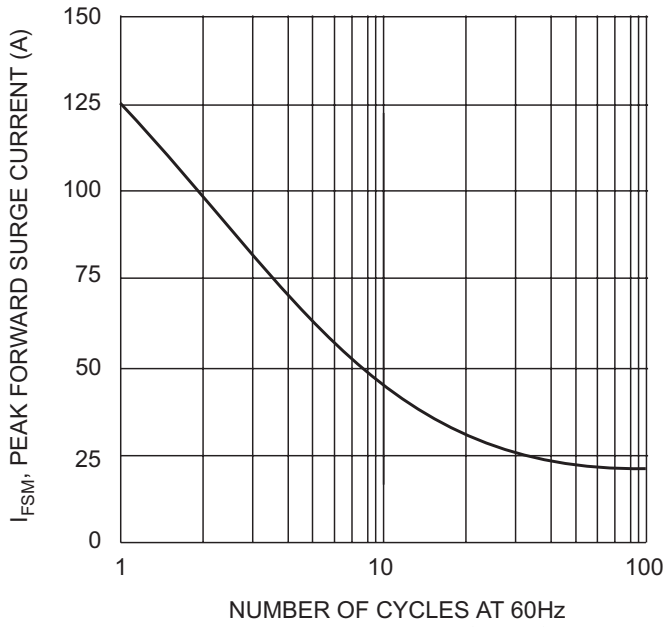


Fig. 3 Max Non-Repetitive Surge Current

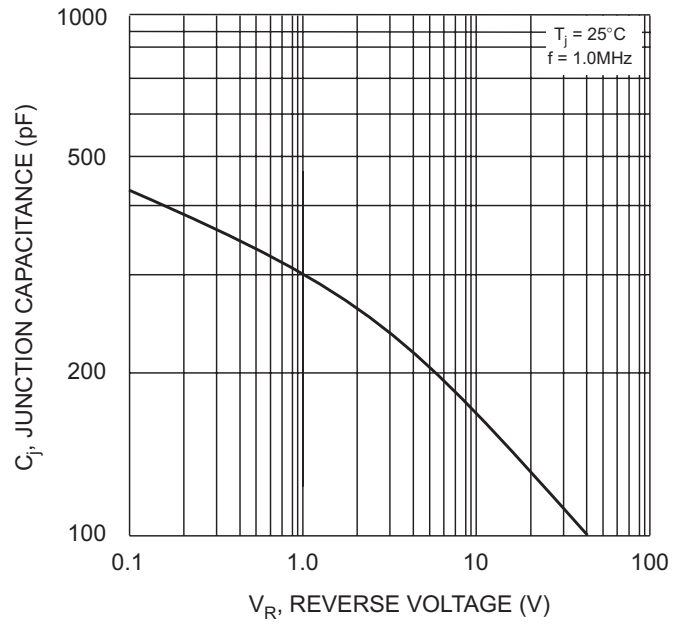


Fig. 4 Typical Junction Capacitance

**Ordering Information** (Note 4)

Device	Packaging	Shipping
SBG1030CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG1035CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG1040CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch
SBG1045CT-T-F	D <sup>2</sup> PAK	800/Tape & Reel, 13-inch

Notes: 4. For packaging details, visit our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

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